

## ESD PROTECTION DEVICE

STAND-OFF VOLTAGE - **5.0** Volts  
POWER DISSIPATION - **130** WATTS

### FEATURES

- Protects up to four I/O lines & power line
- Low capacitance: 0.3pF typical (I/O to I/O)
- Low clamping voltage
- IEC 61000-4-2 ( ESD ), > ±30KV ( air ) ; > ±9KV ( contact )

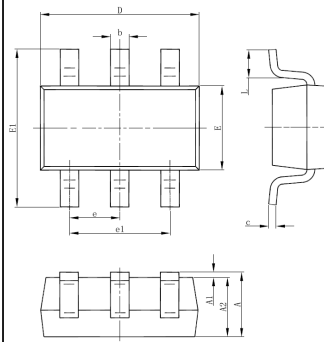
### APPLICATION

- High Definition Multimedia Interface (HDMI)
- Digital Visual Interface (DVI)
- Monitors and Flat Panel Displays
- USB 2.0
- USB OTG
- IEEE 1394 Firewire Port

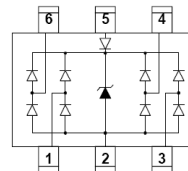
### MECHANICAL DATA

- Case Material: "Green" molding compound UL flammability classification 94V-0 (No Br,Sb, Cl)
- Terminals: Lead Free Plating (Matte Tin Finish)
- Component in accordance to RoHs 2002/95/E

### SOT23-6L



SOT23-6L		
DIM.	MIN.	MAX.
A	0.90	1.45
A1	0.00	0.15
A2	0.90	1.30
b	0.30	0.50
c	0.08	0.22
D	2.45	3.00
E	1.50	1.75
E1	2.80 typ.	
e	0.95 typ.	
e1	1.90 typ.	
L	0.30	0.60
All Dimensions in millimeter		



4 lines Protection

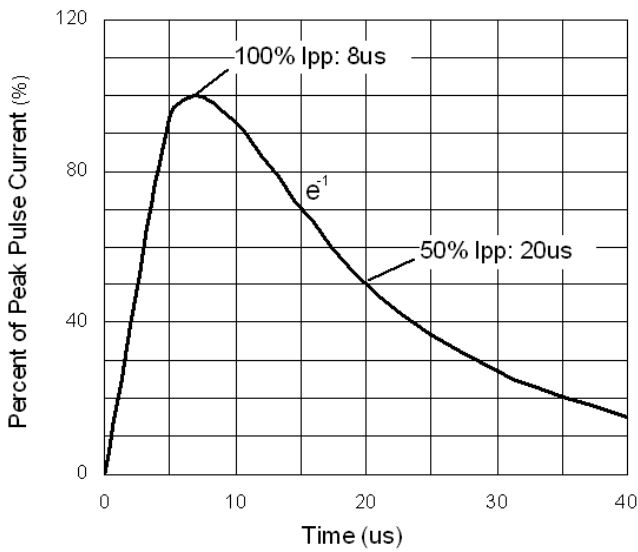
PIN ASSIGNMENT	
1, 3, 4, 6	I/O Lines
5	V <sub>CC</sub>
2	Ground

### MAXIMUM RATINGS (T<sub>j</sub>= 25°C unless otherwise noticed)

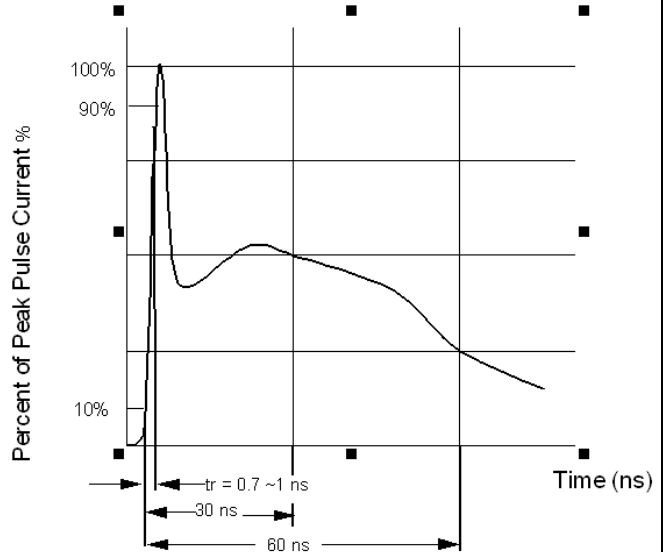
Rating	Symbol	Value	Unit
Peak Pulse Power (tp = 8/20us)	P <sub>pk</sub>	130	W
Peak Pulse Current (tp = 8/20us)	I <sub>pp</sub>	5	A
Operating Junction Temperature Range	T <sub>J</sub>	-55 to + 125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to + 150	°C
Soldering Temperature, t max = 10s	T <sub>L</sub>	260	°C

### ELECTRICAL CHARACTERISTICS (T<sub>j</sub>= 25°C unless otherwise noticed)

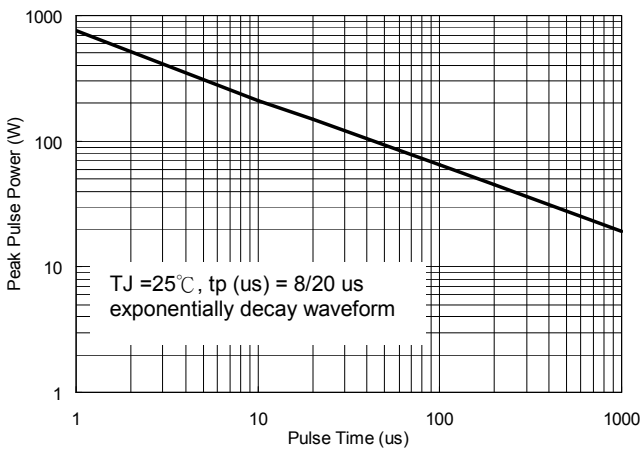
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse standoff voltage	V <sub>RWM</sub>	Any pin to ground	---	---	5.0	V
Breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 1 mA	6.0	---	---	V
Reverse leakage current	I <sub>RM</sub>	V <sub>DRM</sub> = 5V	---	---	1	uA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 1A, tp = 8/20μs, Any I/O pin to ground	---	---	15	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5A, tp = 8/20μs, Any I/O pin to ground	---	---	26	V
Junction capacitance	C <sub>J</sub>	V <sub>R</sub> = 2.5V, f = 1MHz, Any I/O pin to ground	---	---	0.8	pF
Junction capacitance	C <sub>J</sub>	V <sub>R</sub> = 2.5V, f = 1MHz, Between I/O pins	---	---	0.4	pF



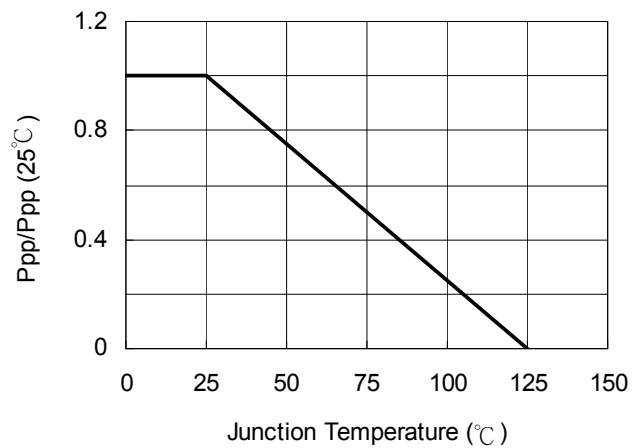
**Figure 1. 8/20 us pulse waveform according to IEC 61000-4-5**



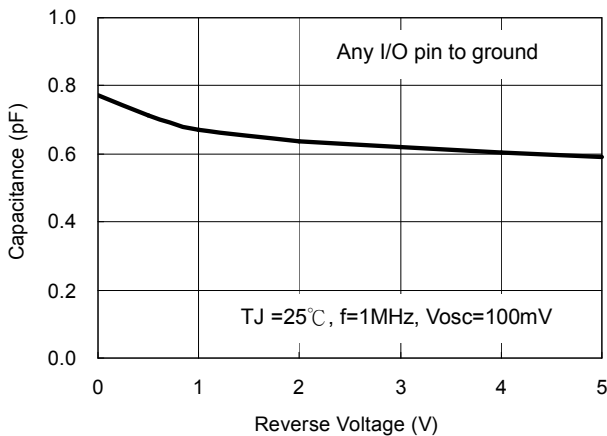
**Figure 2. ESD pulse waveform according to IEC 61000-4-2**



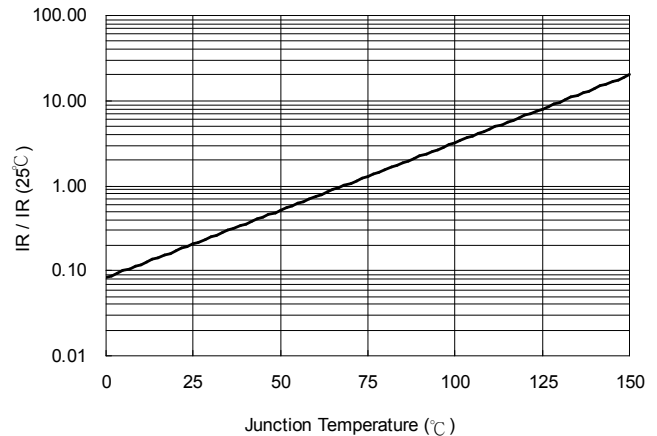
**Figure 3. Power Dissipation versus Pulse Time**



**Figure 4. Peak pulse power versus TJ**



**Figure 5. Typical Junction Capacitance**



**Figure 6. Reverse Leakage Current versus TJ**

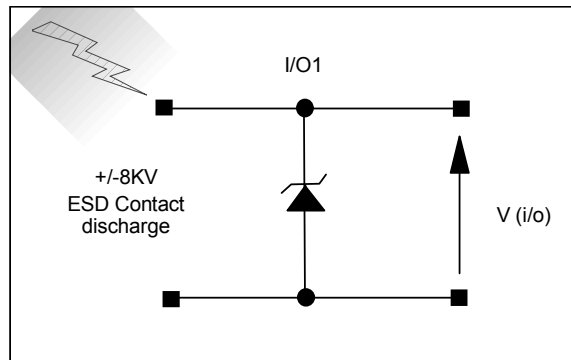


Figure 7. ESD Test Configuration

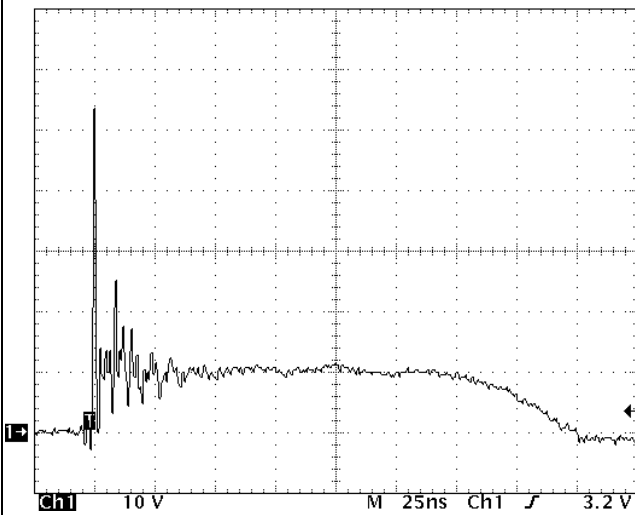


Figure 8. Clamped +8 kV ESD voltage waveform

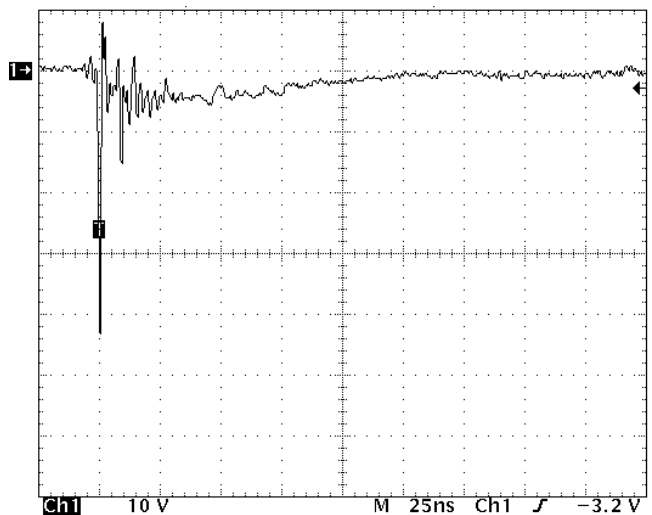
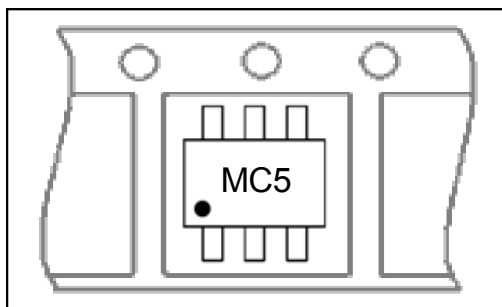
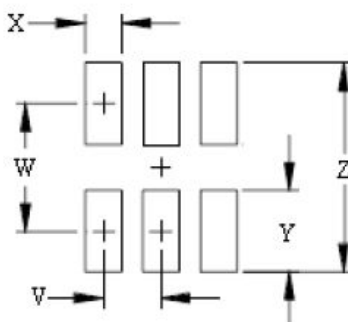


Figure 9. Clamped -8 kV ESD voltage waveform

## Marking & Orientation



## SOT23-6L Soldering Pad Layout



Dim.	Millimeters	Inches
Z	3.60	0.141
X	0.80	0.031
W	2.60	0.102
Y	1.00	0.039
V	0.95	0.037